

ES2DBF THRU ES2JBF

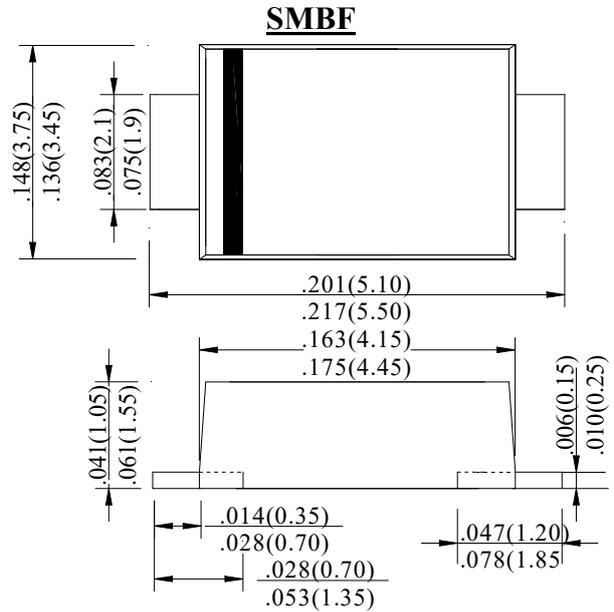
2.0AMPS. SUPER FAST SURFACE MOUNT RECTIFIER

FEATURE

- . High current capability
- . Low forward voltage drop
- . Low power loss, high efficiency
- . High surge capability
- . High temperature soldering guaranteed:
260°C/10 seconds at terminals.
- . Superfast recovery time for high efficiency.
- . For surface mounted application.
- . Easy pick and place.

MECHANICAL DATA

- . Case: Molded plastic
- . Epoxy: UL94V-0 rate flame retardant
- . Lead: MIL-STD- 202E, Method 208 guaranteed
- . Polarity:Color band denotes cathode end
- . Packaging:12mm tape per EIA STD RS-481
- . Mounting position: Any



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz,resistive or inductive load. For capacitive load, derate current by 20%

Type Number	SYM BOL	ES2DBF	ES2GBF	ES2JBF	units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	200	400	600	V
Maximum RMS Voltage	V_{RMS}	140	280	420	V
Maximum DC blocking Voltage	V_{DC}	200	400	600	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	2.0			A
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load (JEDEC method)	I_{FSM}	50.0			A
Maximum Forward Voltage at 2.0A DC	V_F	0.95	1.3	1.7	V
Maximum DC Reverse Current @ $T_J=25^{\circ}C$ at rated DC blocking voltage @ $T_J=125^{\circ}C$	I_R	5.0 100.0			μA
Maximum Reverse Recovery Time (Note 1)	t_{rr}	35			nS
Typical Junction Capacitance (Note 2)	C_J	18	12		pF
Typical Thermal Resistance (Note 3)	$R_{(JA)}$	60			$^{\circ}C/W$
Storage Temperature	T_{STG}	-55 to +150			$^{\circ}C$
Operation Junction Temperature	T_J	-55 to +150			$^{\circ}C$

Note:

1. Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $IRR=0.25A$
2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
3. Measured on P.C.Board with 15.0×15.0mm Copper Pad Areas.

RATING AND CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

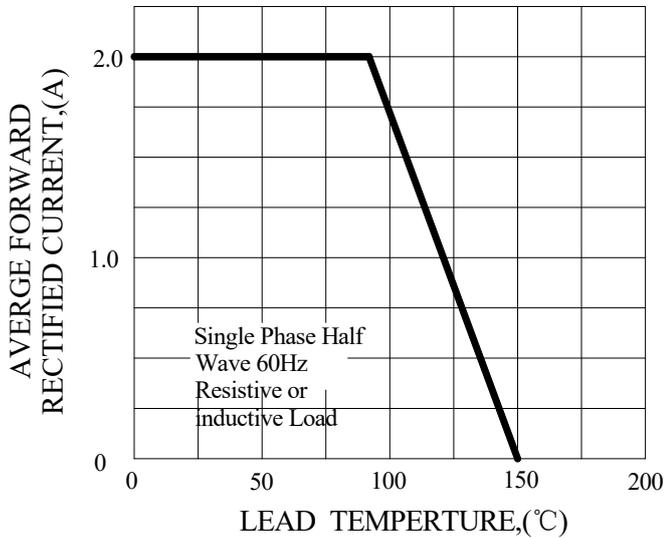


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

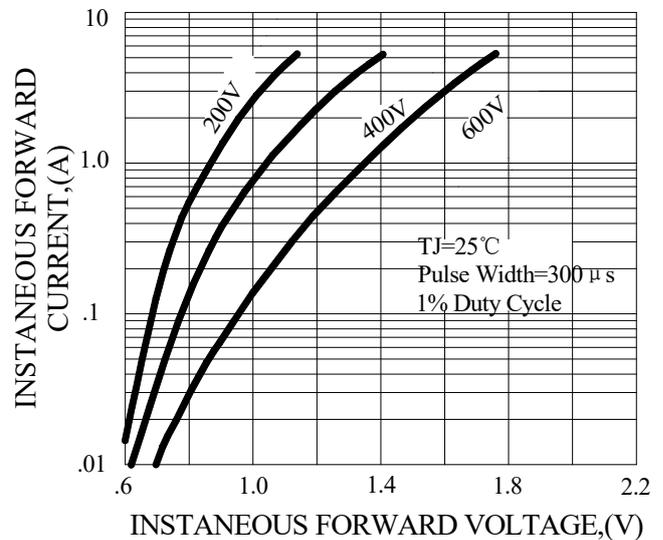


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

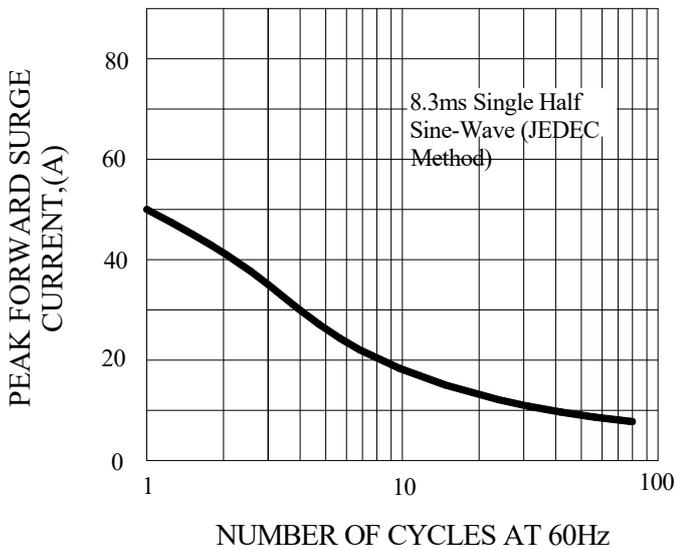


FIG.4-TYPICAL REVERSE CHARACTERISTICS

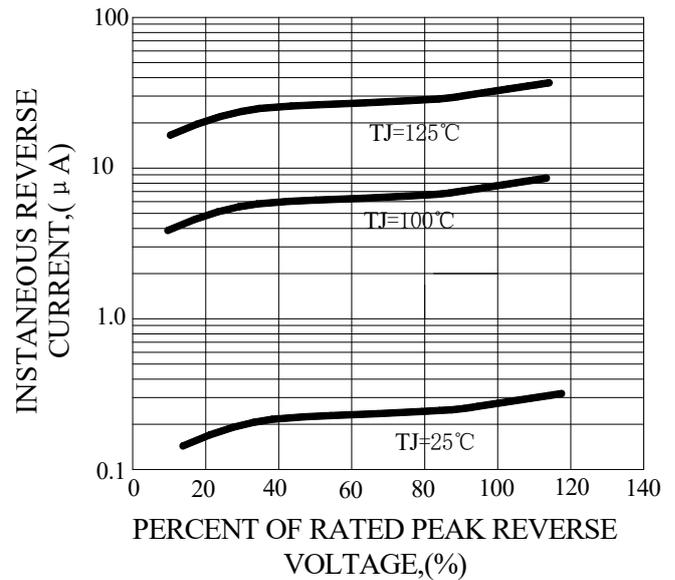
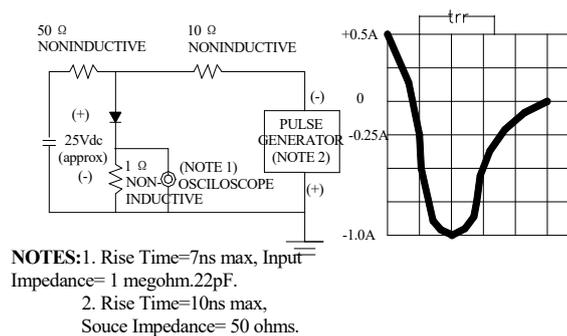
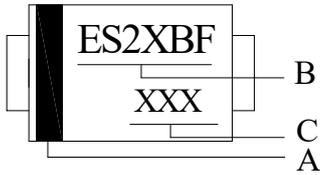


FIG.5-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



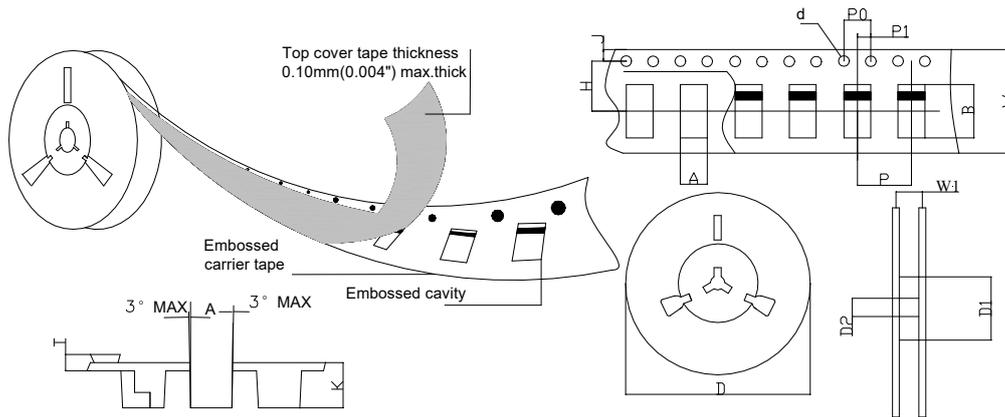
Marking and packaging illustration

1、Marking



SYMBOL	explanation
A	Color Band Denotes Cathode
B	Product name
C	Date code

2、Packaging



SPECIFICATIONS mm(inch)		PACKAGE	SPECIFICATIONS mm(inch)		PACKAGE
ITEM	SYM BOL	SMBF	ITEM	SYM BOL	SMBF
Carrier width	A	3.81(0.150)Max	Carrier depth	K	1.6(0.063)Typ
Carrier length	B	5.61(0.221)Max	Punch hole pitch	P	8.00(0.315)Typ
Sprocket hole	d	ø1.55(0.061)Typ	Sprocket hole pitch	P0	4.00(0.157)Typ
Reel outer diameter	D	330.0(13.0)Typ	Embossment center	P1	2.00(0.079)Typ
Reel inner diameter	D1	153.0(6.02)Min	Overall tape thickness	T	0.30(0.012)Typ
Feed hole diameter	D2	77.0(3.03)Typ	Tape width	W	12.0(0.472)Typ
Sprocket hole position	J	1.75(0.069)Typ	Reel width	W1	12.4(0.488)Min
Punch hole position	H	5.50(0.216)Typ			